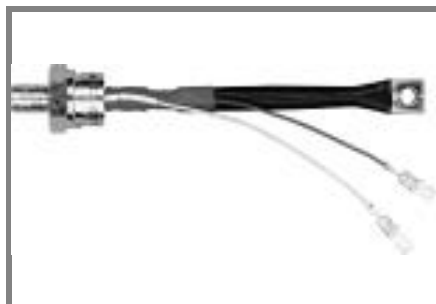




Stud Thyristor

Line Thyristor

SKT 300

Features

- Hermetic metal case with glass insulator
- Threaded stud ISO M24x1,5 or UNF 3/4-16
- High i^2t and I_{TSM} values for easy fusing
- International standard case

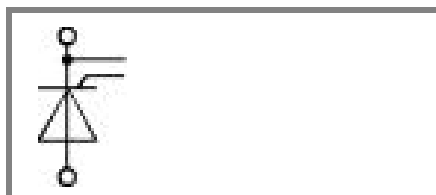
Typical Applications*

- DC motor control (e. g. for machine tools)
- Controlled rectifiers (e. g. for battery charging)
- AC controllers (e. g. for temperature control)
- Recommended snubber network e. g. for $V_{VRMS} \leq 400$ V:
 $R = 33 \Omega / 32$ W, $C = 0,47 \mu F$

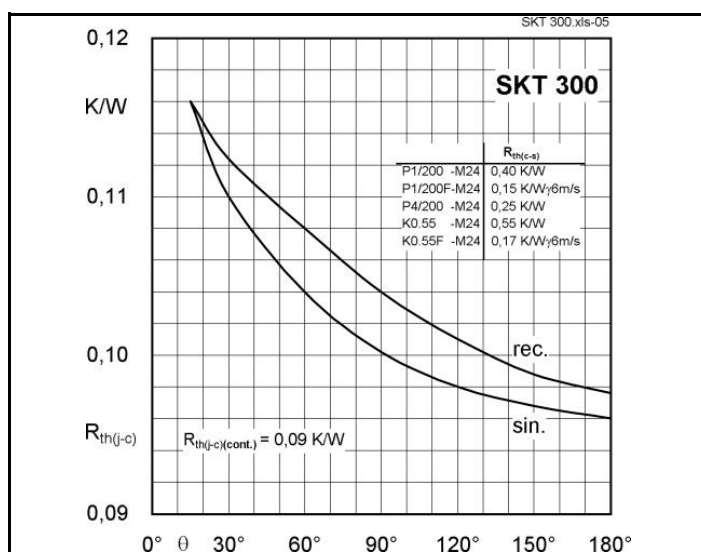
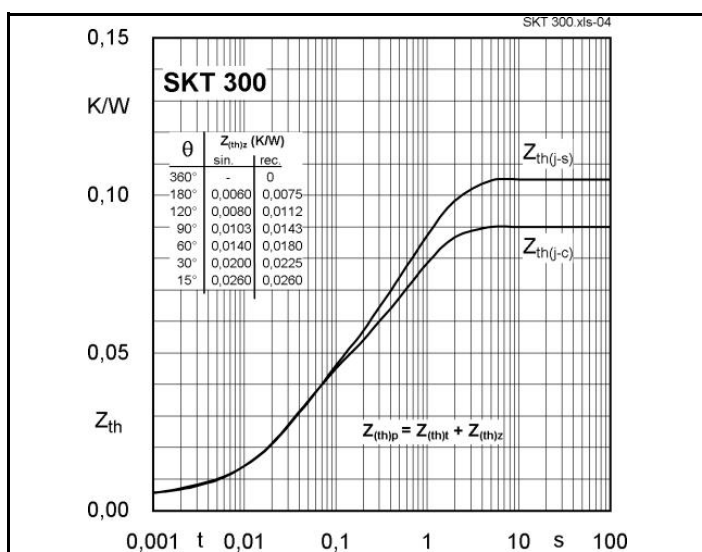
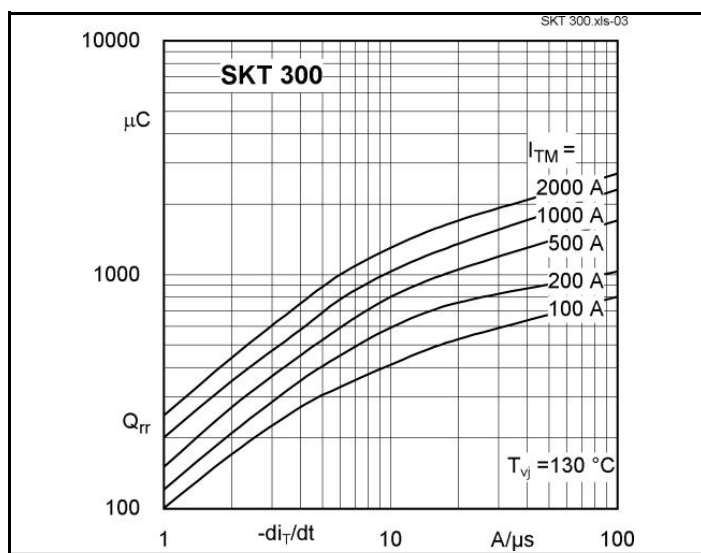
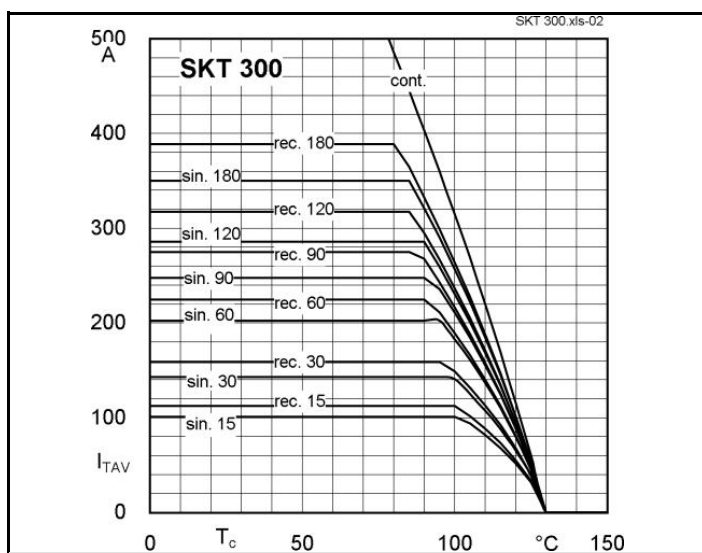
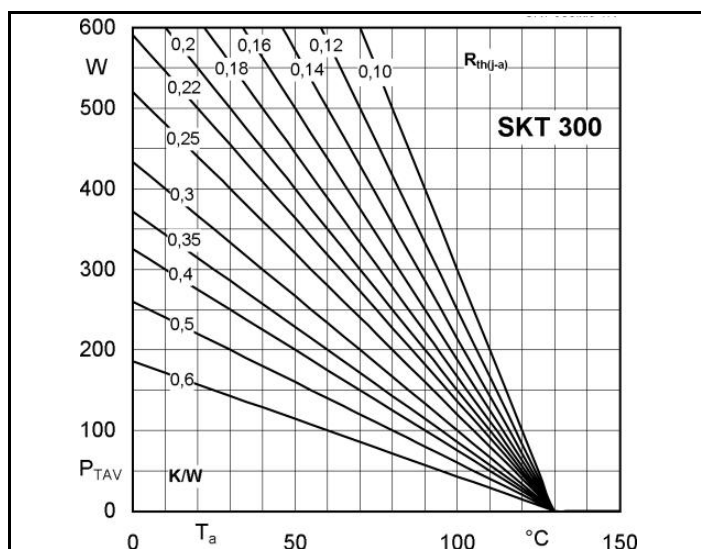
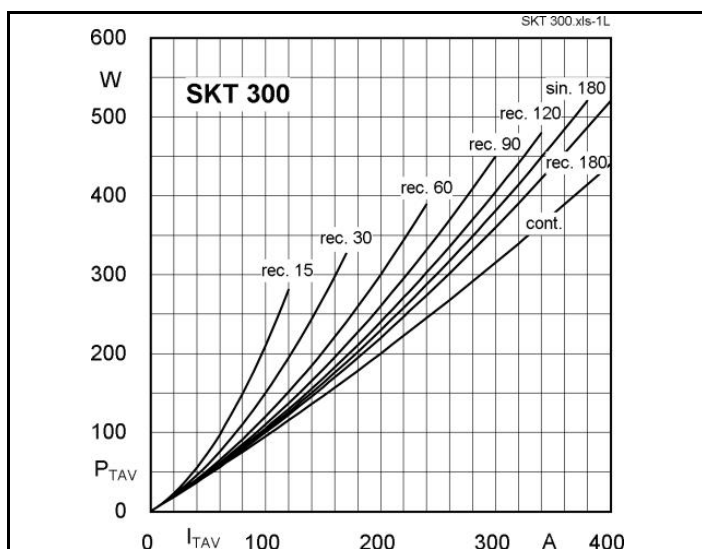
1) available with UNF thread 3/4-16 UNF2A, e. g. SKT 300/08D UNF

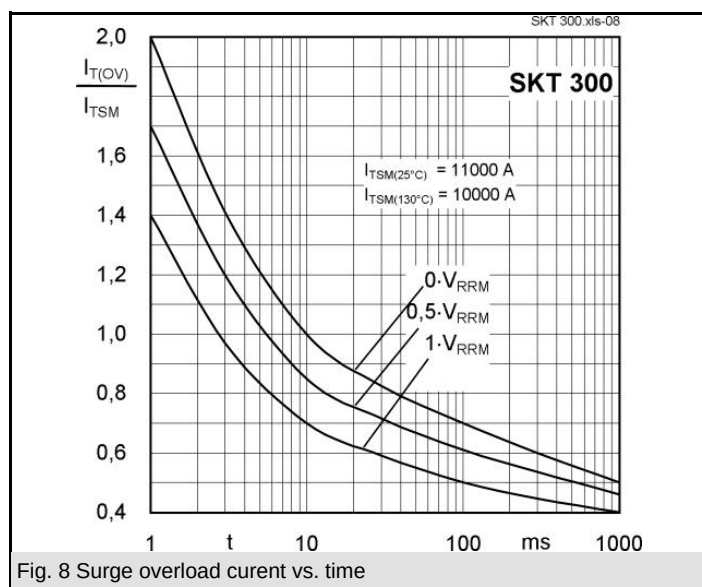
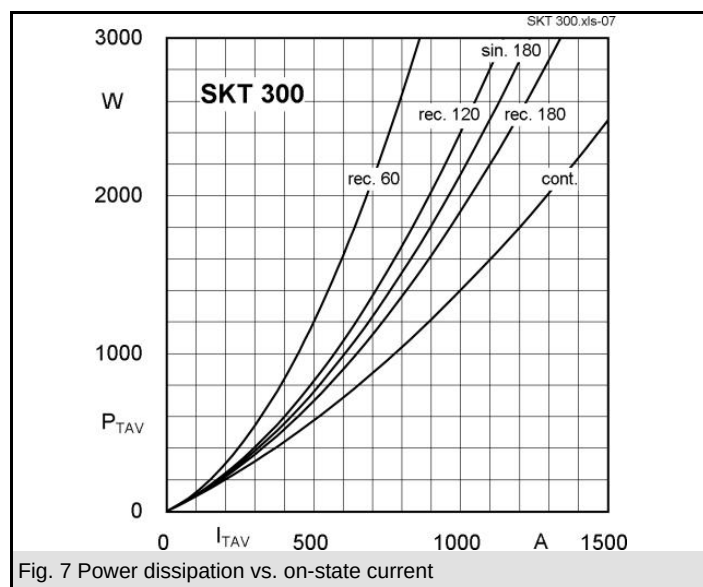
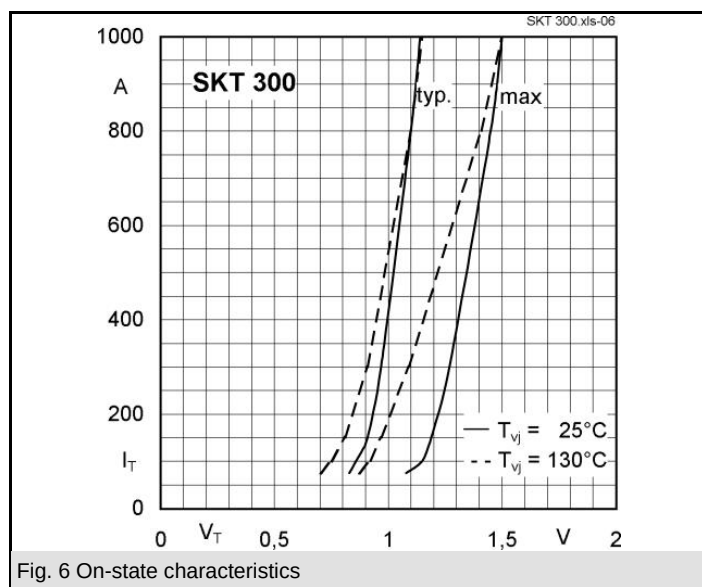
V_{RSM} V	V_{RRM}, V_{DRM} V	$I_{TRMS} = 550$ A (maximum value for continuous operation) $I_{TAV} = 300$ A (sin. 180; $T_c = 93$ °C)		
500	400	SKT 300/04D		
900	800	SKT 300/08D ¹⁾		
1300	1200	SKT 300/12E ¹⁾		
1500	1400	SKT 300/14E ¹⁾		
1700	1600	SKT 300/16E ¹⁾		

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 100$ (85) °C;	257 (351)	A
I_D	K0,55; $T_a = 45$ °C; B2 / B6	250 / 360	A
	K0,55F; $T_a = 35$ °C; B2 / B5	570 / 800	A
I_{RMS}	K0,55; $T_a = 45$ °C; W1C	280	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms	11000	A
	$T_{vj} = 130$ °C; 10 ms	10000	A
i^2t	$T_{vj} = 25$ °C; 8,35 ... 10 ms	600000	A ² s
	$T_{vj} = 130$ °C; 8,35 ... 10 ms	500000	A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 800$ A	max. 1,45	V
$V_{T(TO)}$	$T_{vj} = 130$ °C	max. 0,9	V
r_T	$T_{vj} = 130$ °C	max. 0,5	mΩ
I_{DD}, I_{RD}	$T_{vj} = 130$ °C; $V_{RD} = V_{RRM}, V_{DD} = V_{DRM}$	max. 50	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
t_{gr}	$V_D = 0,67 \cdot V_{DRM}$	2	μs
$(di/dt)_{cr}$	$T_{vj} = 130$ °C	max. 100	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 130$ °C; SKT ...D / SKT ...E	max. 500 / 1000	V/μs
t_q	$T_{vj} = 130$ °C	50 ... 150	μs
I_H	$T_{vj} = 25$ °C; typ. / max.	150 / 250	mA
I_L	$T_{vj} = 25$ °C; $R_G = 33 \Omega$; typ. / max.	300 / 600	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 3	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 200	mA
V_{GD}	$T_{vj} = 130$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 130$ °C; d.c.	max. 10	mA
$R_{th(j-c)}$	cont.	0,09	K/W
$R_{th(j-c)}$	sin. 180	0,096	K/W
$R_{th(j-c)}$	rec. 120	0,101	K/W
$R_{th(c-s)}$		0,015	K/W
T_{vj}		- 40 ... + 130	°C
T_{stg}		- 55 ... + 150	°C
V_{isol}		-	V~
M_s	to heatsink	60 (UNF: 30)	Nm
a		5 * 9,81	m/s ²
m	approx.	490	g
Case		B 7	



SKT





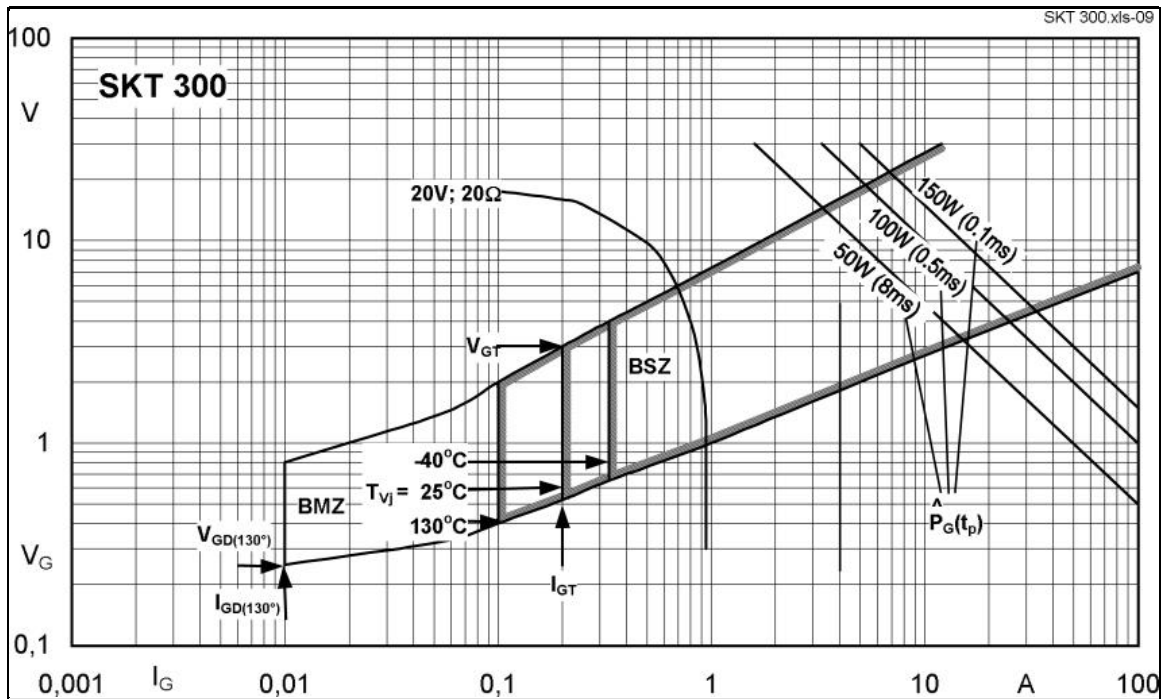
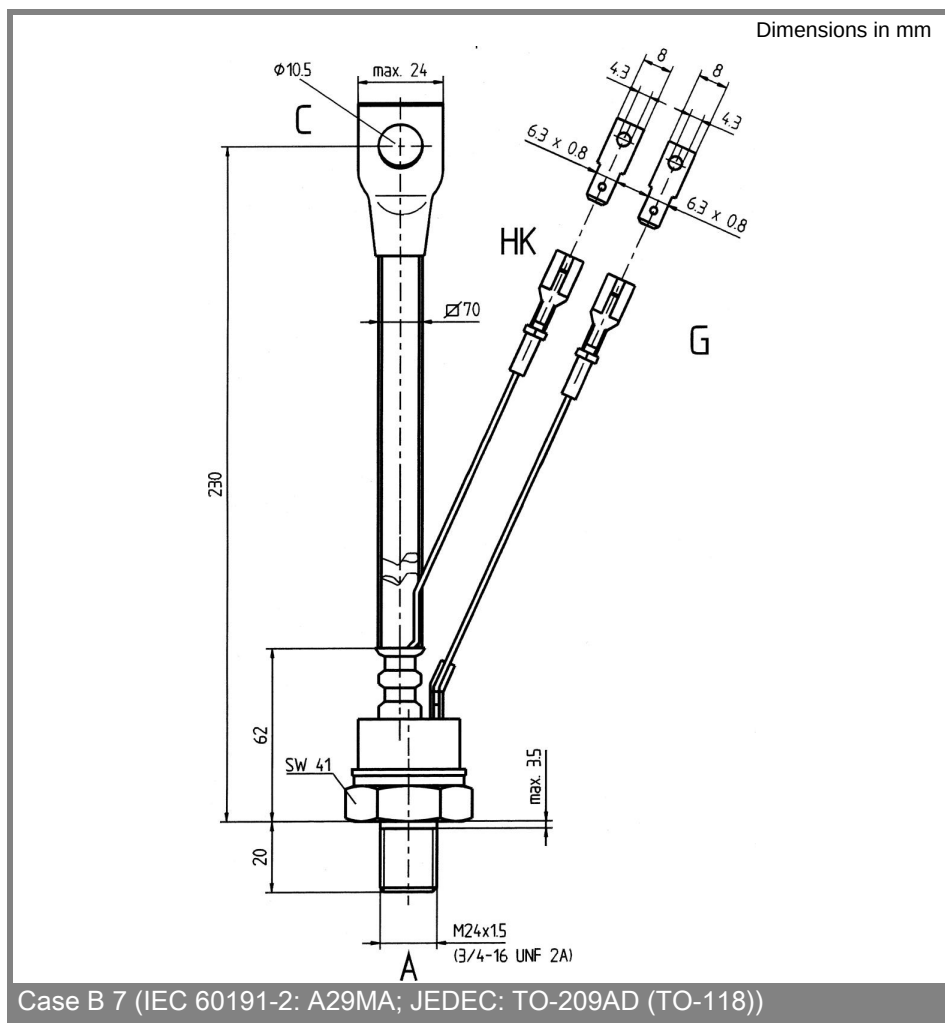


Fig. 9 Gate trigger characteristics



* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON

products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.